



TDF8546

I²C-bus controlled 4 × 45 W best efficiency amplifier

Rev. 8 — 27 September 2013

Product short data sheet

1. General description

The TDF8546 is one of a new generation of complementary quad Bridge-Tied Load (BTL) audio power amplifiers intended for automotive applications. It has a best efficiency mode with full I²C-bus controlled diagnostics, including start-up diagnostics. The TDF8546 can operate at a battery voltage as low as 6 V making this amplifier suitable for stop/start-car operation.

The new best efficiency principle uses a patented switch technique which reduces switching distortion. To reduce power dissipation, the new best efficiency principle uses the audio information on all four channels instead of only the front or rear signals. Dissipation is more than 65 % less than standard BTL when used for front and rear correlated audio signals. Dissipation is 35 % less than standard BTL when used for uncorrelated (delayed) audio signals between front and rear. It is 17 % less for uncorrelated audio signals when the front or rear information is used.

The amplifier uses a complementary DMOS output stage in a Silicon-On-Insulator (SOI) based BCD process. The DMOS output stage ensures a high-power output signal with perfect sound quality. The SOI-based BCD process ensures a robust amplifier, where latch-up cannot occur, with good separation between the four independent channels, with every component isolated and without substrate currents.

2. Features and benefits

- Stop/start-car prepared: keeps operating without audible disturbance during engine start at a battery voltage as low as 6 V
- New best efficiency mode with patented low switching distortion
- Extreme best efficiency mode (uses information from 4 channels) with 17 % less dissipation for uncorrelated signals compared to 2-channel best efficiency mode.
- Operates in either legacy (non-I²C-bus) or I²C-bus modes (3.3 V and 5 V compliant)
- Four hardware-programmable I²C-bus addresses
- Can drive 2 Ω and 4 Ω loads
- Speaker fault detection
- Start-up diagnostics with load detection: open, short, present; filtered for door-slam and chatter relays
- AC load (tweeter) detection with low and high current mode
- Gain select after start-up without audible disturbance
- Independent selectable soft mute of front and rear channels
- Programmable gain (26 dB and 16 dB), independently programmable for the front and rear channels



- Line driver mode supports engine start at a battery voltage as low as 6 V (16 dB and mid-tap voltage $0.25 \times V_P$)
- Programmable clip detect: 2 %, 5 % or 10 %
- Programmable thermal pre-warning
- Pin STB can be programmed/multiplexed with second-clip detect
- Clip information of each channel can be directed separately to pin DIAG or pin STB
- Independent enabling of thermal-, clip- or load fault information (short across the load or to V_P or to ground) on pin DIAG
- Loss-of-ground and open V_P safe (minimum series resistance required)
- All amplifier outputs short-circuit proof to ground, supply voltage and across the load (channel independent)
- All pins short-circuit proof to ground
- Temperature controlled gain reduction to prevent audio holes at high junction temperatures
- Programmable low battery voltage detection to enable 7.5 V or 6 V minimum battery voltage operation
- Overvoltage protection (load-dump safe up to $V_P = 50$ V) with overvoltage pre-warning at 16 V
- Offset detection

3. Quick reference data

Table 1. Quick reference data

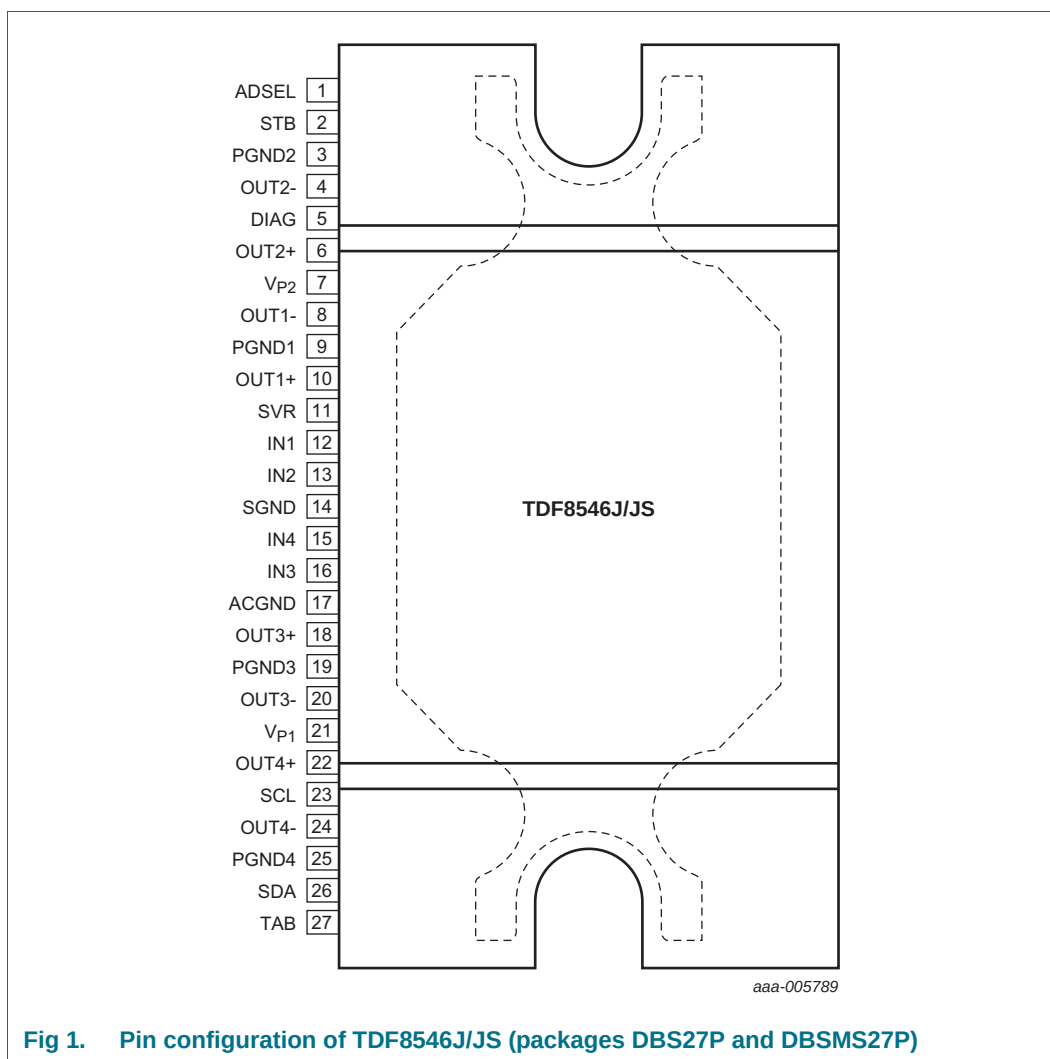
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{P(oper)}$	operating supply voltage	$R_L = 4 \Omega$	6	14.4	18	V
I_q	quiescent current	no load	-	260	350	mA
		no load; $V_P = 7$ V	-	190	-	mA
P_o	output power	$R_L = 4 \Omega$; $V_P = 14.4$ V; maximum power; $V_i = 2$ V RMS square wave	37	40	-	W
		$R_L = 4 \Omega$; $V_P = 15.2$ V; maximum power; $V_i = 2$ V RMS square wave	41	45	-	W
		$R_L = 4 \Omega$; $V_P = 14.4$ V; THD = 0.5 %	18	20	-	W
		$R_L = 4 \Omega$; $V_P = 14.4$ V; THD = 10 %	23	25	-	W
		$R_L = 2 \Omega$; $V_P = 14.4$ V; THD = 10 %	40	44	-	W
		$R_L = 2 \Omega$; $V_P = 14.4$ V; maximum power; $V_i = 2$ V RMS square wave	58	64	-	W
		$P_o = 1$ W to 12 W; $f_i = 1$ kHz; $R_L = 4 \Omega$; BTL mode	-	0.01	0.1	%
THD	total harmonic distortion	$P_o = 4$ W; $f_i = 1$ kHz; $R_L = 4 \Omega$; best efficiency mode	-	0.03	-	%
$V_{n(o)}$	output noise voltage	filter 20 Hz to 22 kHz; $R_S = 1$ k Ω				
		amplifier mode	-	43	65	μ V
		line driver mode	-	25	33	μ V

4. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
TDF8546J	DBS27P	plastic DIL-bent-SIL (special bent) power package; 27 leads (lead length 6.8 mm)	SOT827-1
TDF8546TH	HSOP36	plastic, heatsink small outline package; 36 leads; low stand-off height	SOT851-1
TDF8546JS	DBSMS27P	plastic dual bent surface mounted SIL power package; 27 leads	SOT1154-1

5.1 Pinning



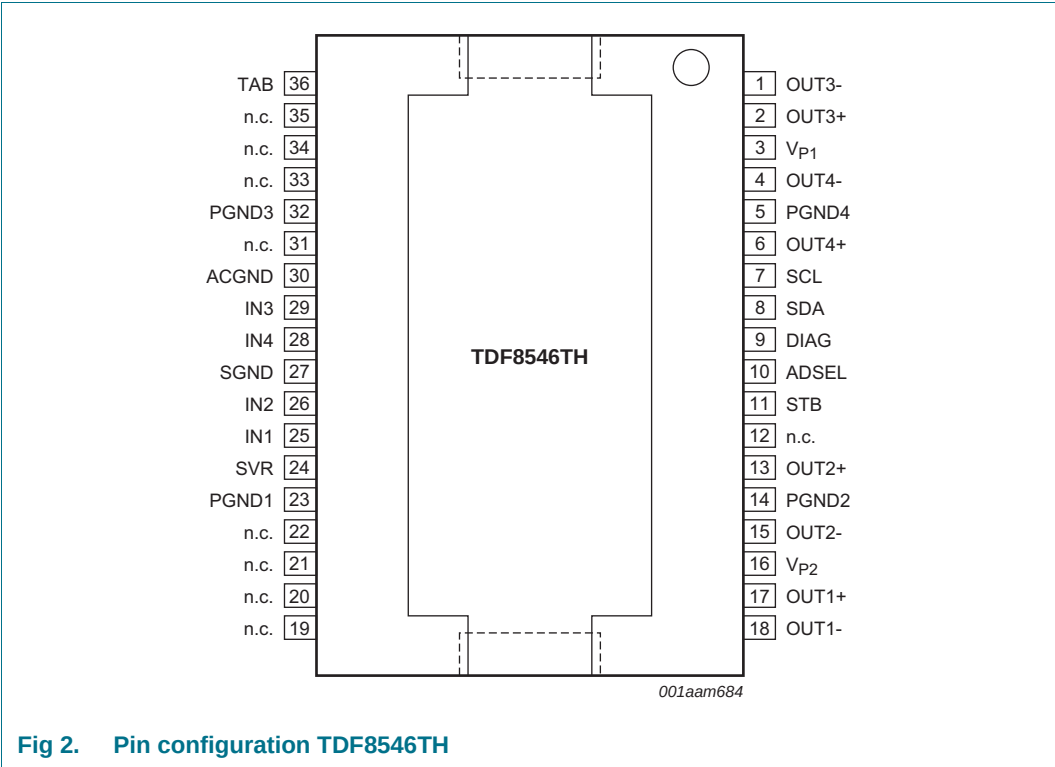


Fig 2. Pin configuration TDF8546TH

5.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	TDF8546J/JS	TDF8546TH	
ADSEL	1	10	I ² C-bus address select
STB	2	11	Standby (I ² C-bus mode) or mode pin (legacy mode) programmable second clip indicator
PGND2	3	14	channel 2 power ground
OUT2–	4	15	channel 2 negative output (right rear)
DIAG	5	9	diagnostic and clip detection output
OUT2+	6	13	channel 2 positive output (right rear)
V _{P2}	7	16	power supply voltage 2
OUT1–	8	18	channel 1 negative output (right front)
PGND1	9	23	channel 1 power ground
OUT1+	10	17	channel 1 positive output (right front)
SVR	11	24	half supply voltage filter capacitor
IN1	12	25	channel 1 input
IN2	13	26	channel 2 input
SGND	14	27	signal ground
IN4	15	28	channel 4 input
IN3	16	29	channel 3 input
ACGND	17	30	AC ground
OUT3+	18	2	channel 3 positive output (left front)
PGND3	19	32	channel 3 power ground
OUT3–	20	1	channel 3 negative output (left front)
V _{P1}	21	3	power supply voltage 1
OUT4+	22	6	channel 4 positive output (left rear)
SCL	23	7	I ² C-bus clock input
OUT4–	24	4	channel 4 negative output (left rear)
PGND4	25	5	channel 4 power ground
SDA	26	8	I ² C-bus data input and output
TAB	27	36	heatsink connection; must be connected to ground
n.c.	-	12, 19, 20, 21, 22, 31, 33, 34, 35	not connected

6. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
DBS27/DBSMS27P				
$R_{th(j-c)}$	thermal resistance from junction to case		1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient		40	K/W
HSOP36				
$R_{th(j-c)}$	thermal resistance from junction to case		1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient		35	K/W

7. Characteristics

Table 5. Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_P = 14.4\text{ V}$; unless otherwise specified. Tested at $T_{amb} = 25\text{ }^{\circ}\text{C}$; guaranteed for $T_j = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; functionality is guaranteed for $V_P < 10\text{ V}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Supply voltage behavior						
$V_{P(oper)}$	operating supply voltage	$R_L = 4\text{ }\Omega$	6	14.4	18	V
		$R_L = 2\text{ }\Omega$	6	14.4	16	V
I_q	quiescent current	no load	-	260	350	mA
		no load; $V_P = 7\text{ V}$	-	190	-	mA
I_{off}	off-state current	$V_{STB} = 0.4\text{ V}$	-	4	10	μA
V_O	output voltage	DC				
		amplifier on; high gain/low gain mode	6.6	7.1	7.6	V
		line driver mode; IB4[D2] = 0; IB3[D5:D6] = 1	3.0	3.4	3.8	V
$V_{P(low)(mute)}$	low supply voltage mute	rising supply voltage				
		IB4[D0] = 1	7.0	7.7	8.1	V
		IB4[D0] = 0	5.4	5.7	6.2	V
		falling supply voltage				
		IB4[D0] = 1	6.5	7.2	7.7	V
$\Delta V_{P(low)(mute)}$	low supply voltage mute hysteresis	IB4[D0] = 1	0.1	0.5	0.8	V
		IB4[D0] = 0	0.1	0.3	0.7	V
$V_{P(ovp)pwarn}$	pre-warning overvoltage protection supply voltage	rising supply voltage	15.2	16	16.9	V
		falling supply voltage	14.4	15.2	16.2	V
		hysteresis	-	0.8	-	V
$V_{th(ovp)}$	overvoltage protection threshold voltage	rising supply voltage	18	20	22	V
V_{POR}	power-on reset voltage	falling supply voltage	-	3.1	4.5	V
$V_{O(offset)}$	output offset voltage	amplifier on	-75	0	+75	mV
		amplifier mute	-25	0	+25	mV
		line driver mode	-45	0	+45	mV

Table 5. Characteristics ...continued

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_P = 14.4\text{ V}$; unless otherwise specified. Tested at $T_{amb} = 25\text{ }^{\circ}\text{C}$; guaranteed for $T_j = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; functionality is guaranteed for $V_P < 10\text{ V}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Mode select and second clip detection: pin STB							
V _{STB}	voltage on pin STB	off-by mode selected					
		I ² C-bus mode	-	-	0.8	V	
		legacy mode (I ² C-bus mode off)	-	-	0.8	V	
		mute selected					
		legacy mode (I ² C-bus mode off)	2.5	-	4.5	V	
		operating mode selected					
		I ² C-bus mode	2.5	-	V _P	V	
		legacy mode (I ² C-bus mode off)	5.9	-	V _P	V	
		low voltage on pin STB when pulled LOW during clipping; clip detection on STB active	[1]				
		I _{STB} = 150 μA	5.6	5.9	6.5	V	
I _{STB} = 500 μA	6.1	-	7.4	V			
I _{STB}	current on pin STB	0 V < V _{STB} < 8.5 V; clip detection not active	[1]	-	5	30	μA
Start-up/shut-down/mute timing							
t _{wake}	wake-up time	time after wake-up via pin STB before first I ² C-bus transmission is recognized;	-	300	500	μs	
I _{LO(SVR)}	output leakage current on pin SVR		-	-	5	μA	
t _{d(mute_off)}	mute off delay time	time from amplifier start to 10 % of output signal; I _{LO} = 0 μA	[2]				
		I ² C-bus mode; with I _{LO} = 5 μA → +15 ms; no DC-load (IB1[D1] = 0);	-	430	650	ms	
		legacy mode; with I _{LO} = 5 μA → +20 ms; V _{STB} = 7 V; R _{ADSEL} = 0 Ω;	-	430	650	ms	
t _{amp_on}	amplifier on time	time from amplifier start to amplifier on; 90 % of output signal; I _{LO} = 0 μA	[2]				
		I ² C-bus mode; with I _{LO} = 5 μA → +30 ms; no DC-load (IB1[D1] = 0);	-	550	800	ms	
		legacy mode; with I _{LO} = 5 μA → +20 ms; V _{STB} = 7 V; R _{ADSEL} = 0 Ω;	-	550	800	ms	

Table 5. Characteristics ...continued

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_P = 14.4\text{ V}$; unless otherwise specified. Tested at $T_{amb} = 25\text{ }^{\circ}\text{C}$; guaranteed for $T_j = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; functionality is guaranteed for $V_P < 10\text{ V}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{off}	amplifier switch-off time	time to DC output voltage $< 0.1\text{ V}$; [2] $I_{LO} = 0\text{ }\mu\text{A}$				
		I ² C-bus mode; with $I_{LO} = 5\text{ }\mu\text{A} \rightarrow +0\text{ ms}$;	250	500	750	ms
		via pin STB; ($IB4[D6] = 0$); with $I_{LO} = 5\text{ }\mu\text{A} \rightarrow +0\text{ ms}$;	250	500	750	ms
$t_{d(mute-on)}$	delay time from mute to on	from 10 % to 90 % of output signal; $V_i = 50\text{ mV}$; I ² C-bus mode ($IB2[D1, D2] = 1\text{ to }0$) or $IB2(D0 = 1\text{ to }0)$ or legacy mode ($V_{STB} = 3\text{ V to }7\text{ V}$);	5	15	40	ms
$t_{d(soft_mute)}$	soft mute delay time	from 90 % to 10 % of output signal; $V_i = 50\text{ mV}$; I ² C-bus mode ($IB2[D1, D2] = 0\text{ to }1$) or legacy mode ($V_{STB} = 7\text{ V to }3\text{ V}$);	5	15	40	ms
$t_{d(fast_mute)}$	fast mute delay time	from 90 % to 10 % of output signal; $V_i = 50\text{ mV}$; I ² C-bus mode ($IB2[D0] = 0\text{ to }1$, or V_{STB} from $> 5.9\text{ V to }< 0.8\text{ V}$ in $1\text{ }\mu\text{s}$;	-	0.4	1	ms
$t_{(start-Vo(off))}$	engine start to output off time	V_P from $14.4\text{ V to }5\text{ V}$ in 1.5 ms ; $V_o < 0.5\text{ V}$;	-	0.1	1	ms
$t_{(start-SVRoff)}$	engine start to SVR off time	V_P from $14.4\text{ V to }5\text{ V}$ in 1.5 ms ; $V_{SVR} < 0.7\text{ V}$;	-	40	75	ms
I²C-bus interface [3]						
V_{IL}	LOW-level input voltage	pins SCL and SDA	-	-	1.5	V
V_{IH}	HIGH-level input voltage	pins SCL and SDA	2.3		5.5	V
V_{OL}	LOW-level output voltage	pin SDA; $I_L = 5\text{ mA}$	-	-	0.4	V
f_{SCL}	SCL clock frequency		-	400	-	kHz
V_{ADSEL}	voltage on pin ADSEL	I ² C-bus address $A[6:0] = 1101\ 101$				
		$R_{series_ADSEL} = 0\text{ }\Omega$	4	5	11	V
		$R_{series_ADSEL} = 100\text{ k}\Omega$	-	-	V_P	V
$I_{I(ADSEL)}$	input current on pin ADSEL	$V_{STB} = 5\text{ V}$; $V_{ADSEL} = 5\text{ V}$	-	2	10	μA
R_{ADSEL}	resistance on pin ADSEL	I ² C-bus address $A[6:0] = 1101\ 110$	99	100	101	$\text{k}\Omega$
		I ² C-bus address $A[6:0] = 1101\ 111$	29.7	30	30.3	$\text{k}\Omega$
		I ² C-bus address $A[6:0] = 1101\ 010$	9.9	10	10.1	$\text{k}\Omega$
		legacy mode	-	-	0.47	$\text{k}\Omega$
$V_{P(latch)}$	latch supply voltage	does not react to address selection changes	-	-	6	V

Start-up diagnostics

Table 5. Characteristics ...continued

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_P = 14.4\text{ V}$; unless otherwise specified. Tested at $T_{amb} = 25\text{ }^{\circ}\text{C}$; guaranteed for $T_j = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; functionality is guaranteed for $V_P < 10\text{ V}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t _{sudiag}	start-up diagnostic time	from start-up diagnostic command via I ² C-bus until completion of start-up diagnostic; V _O + < 0.1 V; V _O – < 0.1 V (no load) IB1[D1] = 1;	50	130	250	ms
t _{d(sudiag-on)}	start-up diagnostic to on delay time	at 90 % of output signal; IB1[D0:D1] = 11;	-	680	-	ms
V _{offset}	offset voltage	start-up diagnostic offset voltage under no load condition	1.3	2	2.5	V
R _{Ldet(sudiag)}	start-up diagnostic load detection resistance	shorted load				
		high gain; IB3[D6:D5] = 00	-	-	0.5	Ω
		low gain; IB3[D6:D5] = 11	-	-	1.5	Ω
		normal load				
		high gain (IB3[D6:D5] = 00)	1.5	-	20	Ω
		low gain (IB3[D6:D5] = 11)	3.2	-	20	Ω
		line driver load	80	-	200	Ω
		open load	400	-	-	Ω
Amplifier diagnostics						
V _{OL(DIAG)}	LOW-level output voltage on pin DIAG	fault condition; I _{DIAG} = 1 mA	-	-	0.3	V
V _{O(offset_det)}	output voltage at offset detection		±1.0	±1.3	±2.0	V
THD _{clip}	total harmonic distortion clip detection level	V _P > 10 V				
		IB2[D7:D6] = 10	-	10	-	%
		IB2[D7:D6] = 01	-	5	-	%
		IB2[D7:D6] = 00	-	2	-	%
T _{j(AV)(pwarn)}	pre-warning average junction temperature	IB3[D4] = 0 or legacy mode	150	160	170	°C
		IB3[D4] = 1	125	135	145	°C
T _{j(AV)(G(-0.5dB))}	average junction temperature for 0.5 dB gain reduction	V _i = 0.05 V; best efficiency mode turns off when activated	-	175	-	°C
ΔG _(th_fold)	gain reduction of thermal foldback	when all channels switch off	-	20	-	dB
I _o	output current	I ² C-bus mode; IB5[D7] = 0; AC load bit set; peak current				
		IB4[D1] = 1	500	-	-	mA
		IB4[D1] = 0	275	-	-	mA
		I ² C-bus mode; IB5[D7] = 0; AC load bit not set; peak current				
		IB4[D1] = 1	-	-	250	mA
		IB4[D1] = 0	-	-	100	mA

Table 5. Characteristics ...continued

$T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_P = 14.4\text{ V}$; unless otherwise specified. Tested at $T_{amb} = 25\text{ }^{\circ}\text{C}$; guaranteed for $T_j = -40\text{ }^{\circ}\text{C}$ to $+150\text{ }^{\circ}\text{C}$; functionality is guaranteed for $V_P < 10\text{ V}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Amplifier						
P_O	output power	$R_L = 4\text{ }\Omega$; $V_P = 14.4\text{ V}$; THD = 0.5 %	18	20	-	W
		$R_L = 4\text{ }\Omega$; $V_P = 14.4\text{ V}$; THD = 10 %	23	25	-	W
		$R_L = 2\text{ }\Omega$; $V_P = 14.4\text{ V}$; THD = 0.5 %	29	32	-	W
		$R_L = 2\text{ }\Omega$; $V_P = 14.4\text{ V}$; THD = 10 %	40	44	-	W
$P_{O(max)}$	maximum output power	$R_L = 4\text{ }\Omega$; $V_P = 14.4\text{ V}$; $V_i = 2\text{ V}$ RMS square wave	37	40	-	W
		$R_L = 4\text{ }\Omega$; $V_P = 15.2\text{ V}$; $V_i = 2\text{ V}$ RMS square wave	41	45	-	W
		$R_L = 2\text{ }\Omega$; $V_P = 14.4\text{ V}$; $V_i = 2\text{ V}$ RMS square wave	58	64	-	W
THD	total harmonic distortion	$P_O = 1\text{ W}$ to 12 W ; $f_i = 1\text{ kHz}$; $R_L = 4\text{ }\Omega$; BTL mode	-	0.01	0.1	%
		$P_O = 1\text{ W}$; $f_i = 1\text{ kHz}$; $R_L = 4\text{ }\Omega$; $V_P = 7\text{ V}$; BTL and best efficiency mode	-	0.01	0.1	%
		$P_O = 4\text{ W}$; $f_i = 1\text{ kHz}$; $R_L = 4\text{ }\Omega$; best efficiency mode	-	0.03	0.1	%
		$P_O = 1\text{ W}$ to 12 W ; $f_i = 20\text{ kHz}$; $R_L = 4\text{ }\Omega$; best efficiency mode	-	0.3	0.4	%
		$V_O = 1\text{ V}$ (RMS) and 4 V (RMS), $f_i = 1\text{ kHz}$; line driver mode	-	0.02	0.05	%
		$P_O = 1\text{ W}$ to 12 W ; $f_i = 1\text{ kHz}$; $R_L = 4\text{ }\Omega$; low gain mode	-	0.01	0.1	%
α_{CS}	channel separation	best efficiency mode; $R_S = 1\text{ k}\Omega$; $R_{ACGND} = 250\text{ }\Omega$	[4]			
		$f_i = 1\text{ kHz}$	65	80	-	dB
		$f_i = 10\text{ kHz}$	55	65	-	dB
SVRR	supply voltage ripple rejection	$f_i = 1\text{ kHz}$; $R_S = 1\text{ k}\Omega$; $R_{ACGND} = 250\text{ }\Omega$; best efficiency mode; tested at $V_P = 10.5\text{ V}$	[4]	55	70	dB
CMRR	common mode rejection ratio	amplifier mode; $V_{cm} = 0.3\text{ V}$ (p-p); $f_i = 1\text{ kHz}$ to 3 kHz ; $R_S = 1\text{ k}\Omega$; $R_{ACGND} = 250\text{ }\Omega$; best efficiency mode	[4]			
		common mode input to differential output ($V_{O(dif)}$ / $V_{I(cm)}$) + 26 dB)	55	65	-	dB
		common mode input to common mode output ($V_{O(cm)}$ / $V_{I(cm)}$) + 26 dB)	50	58	-	dB

Table 5. Characteristics ...continued

$T_{amb} = 25\text{ °C}$; $V_P = 14.4\text{ V}$; unless otherwise specified. Tested at $T_{amb} = 25\text{ °C}$; guaranteed for $T_j = -40\text{ °C}$ to $+150\text{ °C}$; functionality is guaranteed for $V_P < 10\text{ V}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
ΔV_o	output voltage variation	plop during switch-on and switch-off; best efficiency mode	[5]			
		from off to mute and mute to off	-	-	7.5	mV
		from mute to on and on to mute (soft mute)	-	-	7.5	mV
		from off to on and on to off (start-up diagnostic enabled)	-	-	7.5	mV
$V_{n(o)}$	output noise voltage	filter 20 Hz to 22 kHz (6 th order); $R_S = 1\text{ k}\Omega$				
		mute mode	-	15	23	μV
		line driver mode	-	25	33	μV
		amplifier mode; best efficiency mode	-	43	65	μV
		amplifier mode; best efficiency mode; $R_S = 50\text{ }\Omega$	-	40	60	μV
$G_{v(\text{amp})}$	voltage gain amplifier mode	single-ended in to differential out; best efficiency mode	25.5	26	26.5	dB
$G_{v(\text{ld})}$	voltage gain line driver mode	single-ended in to differential out; best efficiency mode	15.5	16	16.5	dB
Z_i	input impedance	$T_{amb} = -40\text{ °C}$ to $+105\text{ °C}$	38	62	105	$\text{k}\Omega$
		$T_{amb} = 0\text{ °C}$ to 105 °C	55	62	105	$\text{k}\Omega$
α_{mute}	mute attenuation	$V_{o(\text{on})} / V_{o(\text{mute})}$; $V_i = 50\text{ mV}$	80	92	-	dB
$V_{o(\text{mute})(\text{RMS})}$	RMS mute output voltage	$V_i = 1\text{ V RMS}$; filter 20 Hz to 22 kHz	-	16	29	μV
B_p	power bandwidth	-1 dB	-	20 to 20000	-	Hz
$C_{L(\text{crit})}$	critical load capacitance	no oscillation; R_L between $2\text{ }\Omega$ and open load; C_L from all outputs to GND	22	-	-	nF

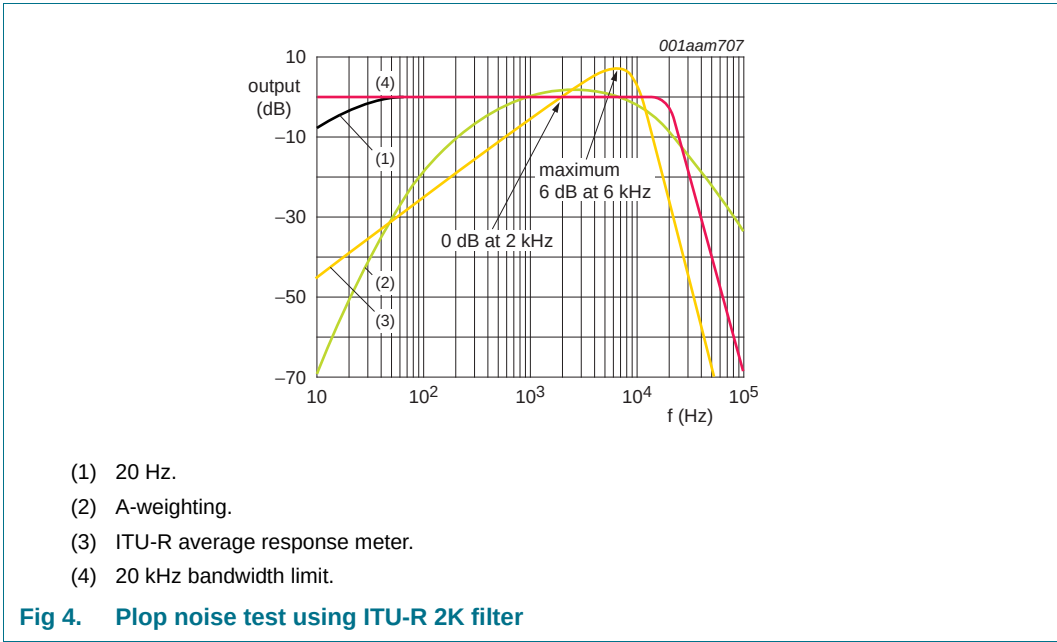
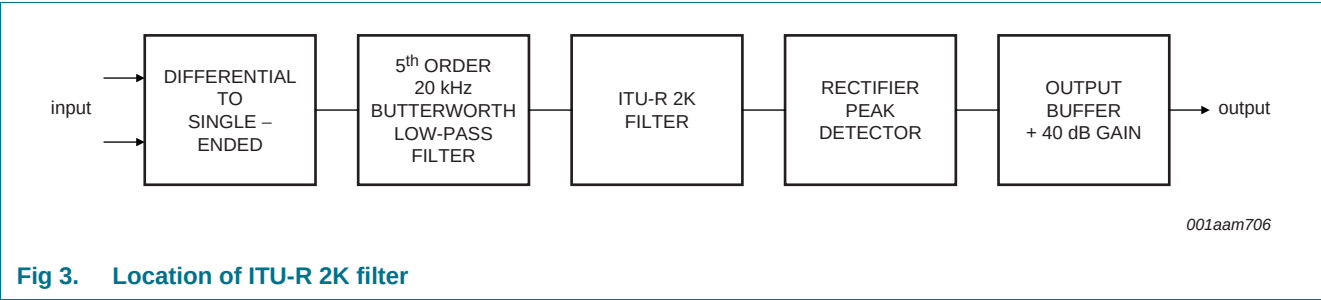
Best efficiency mode control

$V_{o(\text{swoff})\text{be}}$	best efficiency switch-off output voltage	best efficiency switch open				
		4 Ω load selected; IB5[D4] = 1	-	0.9	-	V
		2 Ω load selected; IB5[D4] = 0	-	1.7	-	V
$R_{\text{sw}(\text{be})}$	best efficiency switch resistance		-	1.0	-	Ω

- [1] V_{STB} depends on the current into pin STB: minimum = $(1429\text{ }\Omega \times I_{\text{STB}}) + 5.4\text{ V}$, maximum = $(3143\text{ }\Omega \times I_{\text{STB}}) + 5.6\text{ V}$.
- [2] The times are specified without leakage current. For a leakage current of $5\text{ }\mu\text{A}$ on pin SVR, the delta time is specified. If the capacitor value on pin SVR changes $\pm 30\%$, the specified time also changes $\pm 30\%$. The specified times include an ESR of $15\text{ }\Omega$ for the capacitor on pin SVR.
- [3] Standard I²C-bus specification: maximum LOW-level = $0.3V_{\text{DD}}$, minimum HIGH-level = $0.7V_{\text{DD}}$. To comply with 5 V and 3.3 V logic, $V_{\text{DD}} = 5\text{ V}$ defines the maximum LOW-level and $V_{\text{DD}} = 3.3\text{ V}$ defines the minimum HIGH-level.
- [4] For optimum channel separation (α_{cs}), supply voltage ripple rejection (SVRR) and common mode rejection ratio (CMRR), a resistor

$$R_{\text{ACGND}} = \frac{R_S}{4}\text{ }\Omega \text{ must be in series with the ACGND capacitor.}$$

- [5] The plop-noise during amplifier switch-on and switch-off is measured using an ITU-R 2 k filter; see [Figure 4](#).



8. Package outline

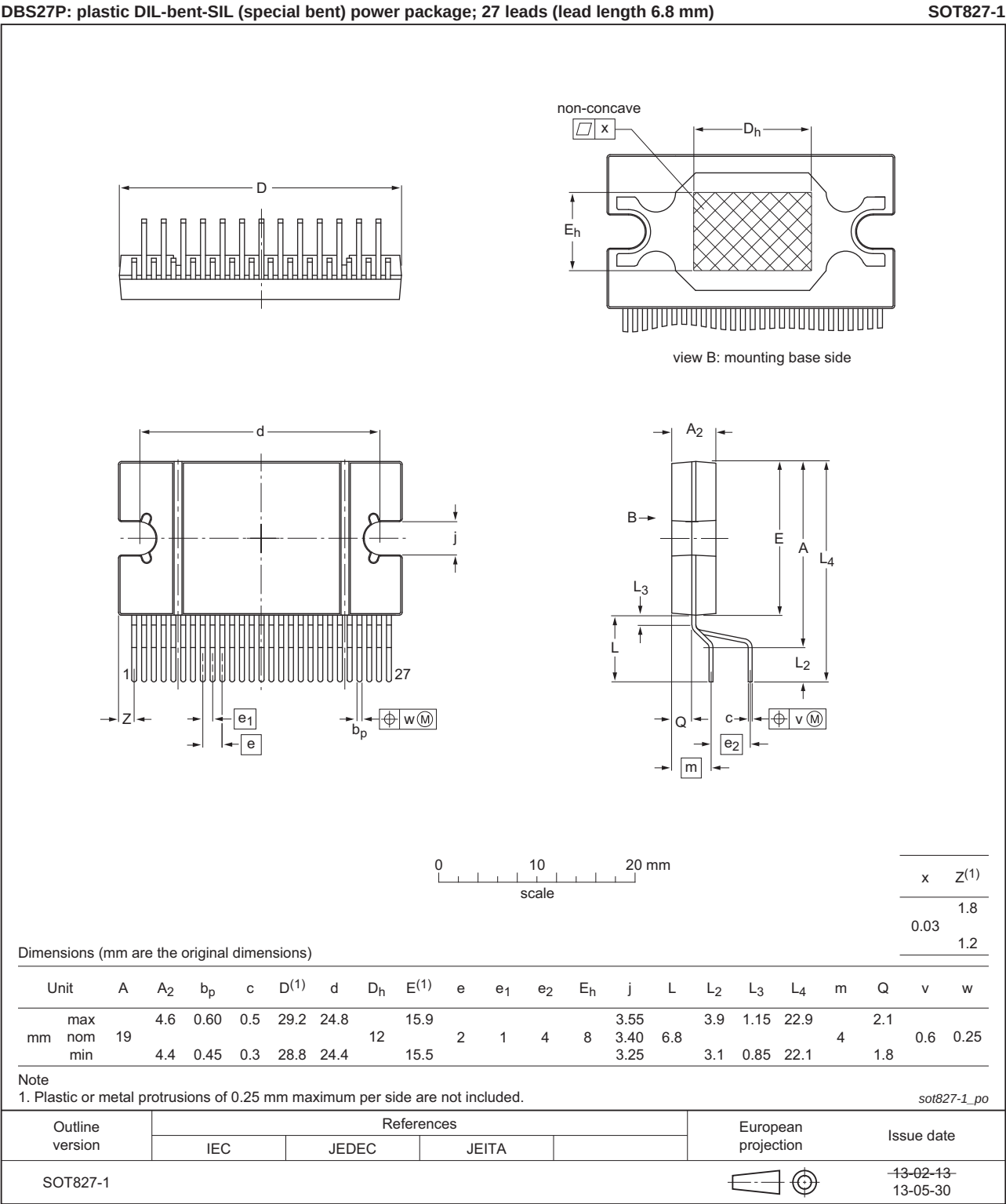


Fig 5. Package outline SOT827-1 (DBS27P)

HSOP36: plastic, heatsink small outline package; 36 leads; low stand-off height

SOT851-1

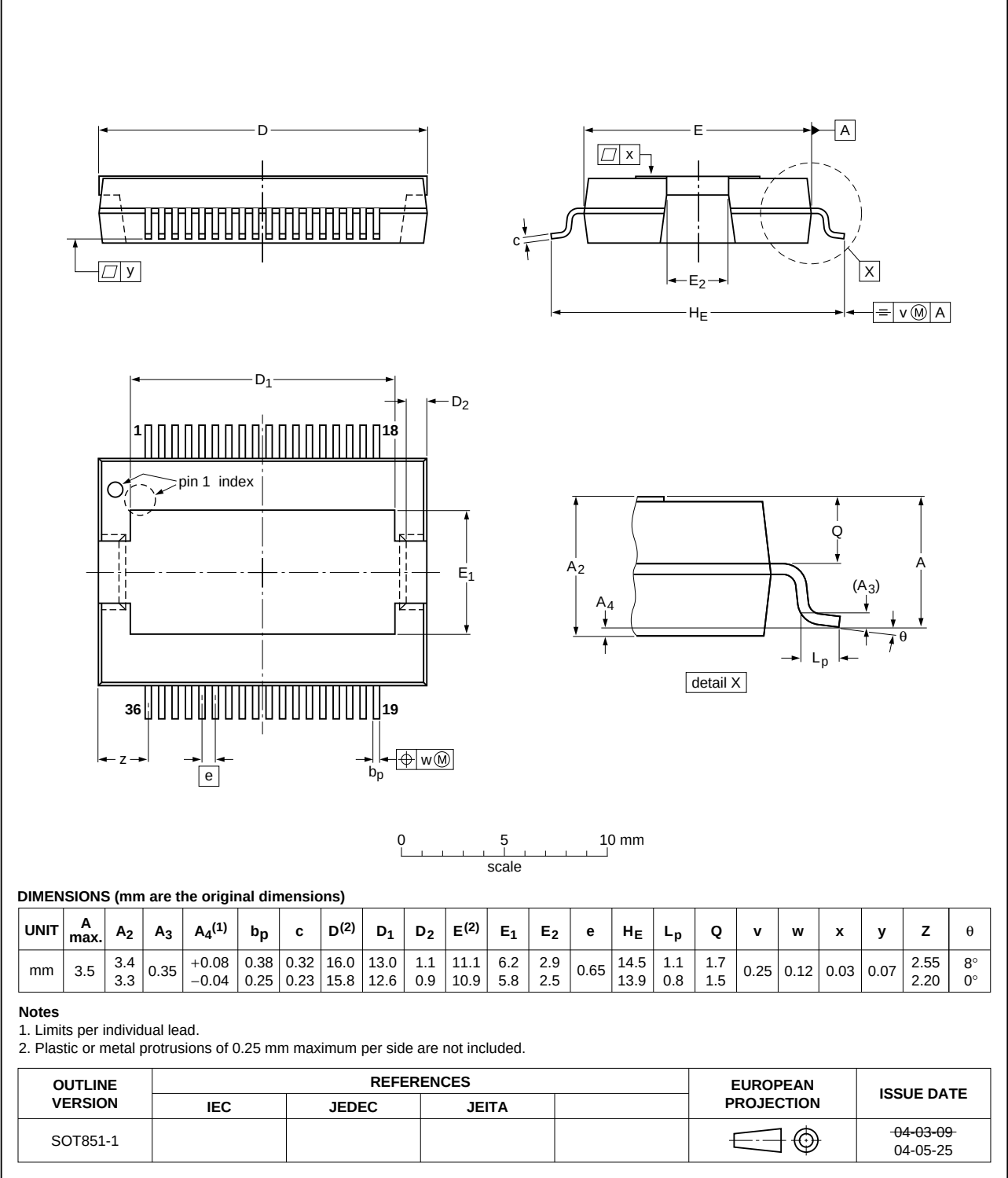


Fig 6. Package outline SOT851-1 (HSOP36)

DBSMS27P: plastic dual bent surface mounted SIL power package; 27 leads

SOT1154-1

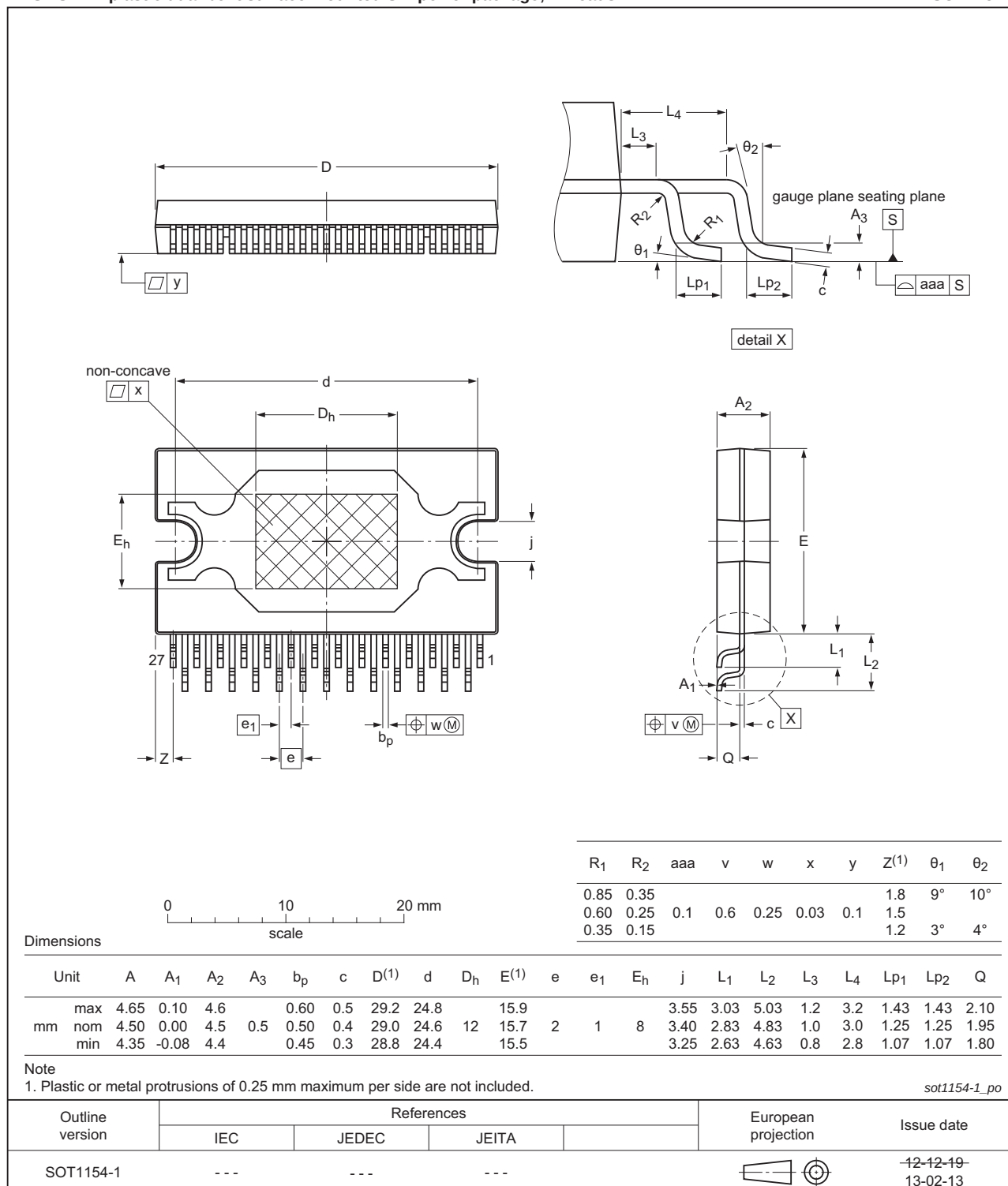


Fig 7. Package outline SOT1154-1 (DBSMS27P)

9. Revision history

Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TDF8546 v.8	20130927	Product short data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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